

General Disclaimer

One or more of the Following Statements may affect this Document

- This document has been reproduced from the best copy furnished by the organizational source. It is being released in the interest of making available as much information as possible.
- This document may contain data, which exceeds the sheet parameters. It was furnished in this condition by the organizational source and is the best copy available.
- This document may contain tone-on-tone or color graphs, charts and/or pictures, which have been reproduced in black and white.
- This document is paginated as submitted by the original source.
- Portions of this document are not fully legible due to the historical nature of some of the material. However, it is the best reproduction available from the original submission.

DISCLAIMER

This report was prepared as an account of work sponsored by an agency of the United States Government. Neither the United States Government nor any agency thereof, nor any of their employees, makes any warranty, express or implied, or assumes any legal liability or responsibility for the accuracy, completeness, or usefulness of any information, apparatus, product, or process disclosed, or represents that its use would not infringe privately owned rights. Reference herein to any specific commercial product, process, or service by trade name, trademark, manufacturer, or otherwise does not necessarily constitute or imply its endorsement, recommendation, or favoring by the United States Government or any agency thereof. The views and opinions of authors expressed herein do not necessarily state or reflect those of the United States Government or any agency thereof.

SAND--83-2362C

THERMAL CONDUCTIVITY BEHAVIOR OF BORON CARBIDES

DE84 003208

Charles Wood* and Andrew Zoltan*

Jet Propulsion Laboratory
California Institute of Technology
Pasadena, CA 91109

David Emin**

Sandia National Laboratories
Albuquerque, NM 87185

Paul E. Gray

GA Technologies
San Diego, CA 92138

ABSTRACT

Knowledge of the thermal conductivity of boron carbide is necessary to evaluate its potential for high temperature thermoelectric energy conversion applications. We have measured the thermal diffusivity of hot-pressed boron carbide $B_{1-x}C_x$ samples as a function of composition ($0.1 \leq x \leq 0.2$), temperature (300 K to 1700 K) and temperature cycling. These data in concert with density and specific heat data yield the thermal conductivities of these materials. We discuss these results in terms of a structural model that has been previously advanced by two of us (D.E. and C.W.) to explain the electrical transport data. Some novel mechanisms for thermal conduction are briefly discussed.

INTRODUCTION

Boron carbides have been utilized extensively in reactor technology for the absorption of thermal neutrons. More recently

DISTRIBUTION OF THIS DOCUMENT IS UNLIMITED

MASTER

EAB

the high-temperature stability and striking electronic transport properties of these and similar semiconducting material (e.g., the boron-rich borides) have sparked interest in their use for high-temperature thermoelectric energy conversion. We have reported elsewhere^{1,2} on the measurement and analysis of the steady-state electrical transport properties of a variety of boron carbides. Here we report on the thermal transport properties of $B_{1-x}C_x$, in the single-phase compositional range $0.1 \leq x \leq 0.2$ from 300 K to 1700 K. Previous reports³⁻⁷ on the thermal transport properties of boron carbides have concentrated solely on the composition $B_{0.8}C_{0.2}(B_4C)$.

Over the compositional range $0.088 \leq x \leq 0.200$ boron carbides are usually viewed as crystallizing in a rhombohedral structure ($D_{3d5}-R\bar{3}m$), the α -boron structure, with deformed icosahedra shared at the corners of the unit cell. A structural unit links icosahedra along a cell diagonal. These units are either three-atom chains^{8,9} or bridged four-boron atom linkage.¹⁰ Carbon atoms are distributed among the icosahedra and the three-atom chains.⁸⁻¹⁰ With increasing carbon content the unit cell shrinks slightly. The melting points of compositions within this single-phase region are about 2600 K.

EXPERIMENTAL PROCEDURE

In this study most boron carbide specimens, $B_{1-x}C_x$, in the single phase regime, $0.088 \leq x \leq 0.200$ were prepared having differing boron to carbon ratios by vacuum (10^{-6} to 10^{-5} torr) hot-pressing (~ 2400 K) at 600 psi for two hours using high-purity (B ~ 30 ppm; C ~ 10 ppm maximum impurities) powders (~ 352 mesh) in boron-nitride lined graphite dies. Similar samples, examined by X-ray diffraction, were found to be single-phase with lattice constants varying with composition essentially in the manner reported by Bouchacourt and Thevenot.¹¹

A heat pulse method^{12,13} was employed to determine the thermal diffusivities. Here a He-Ne laser or Xenon flash lamp applies a heat pulse to one side of a sample. An InSb infrared detector or thermocouple measures the temperature rise of the rear-surface of the sample. Where necessary corrections were applied for heat losses and finite pulse times.¹³ The apparatus was satisfactorily calibrated against the results of an International program¹⁴ on thermal diffusivity measurements of ASM-5Q graphite.

EXPERIMENTAL RESULTS

The thermal diffusivities of various boron carbides, $B_{1-x}C_x$,

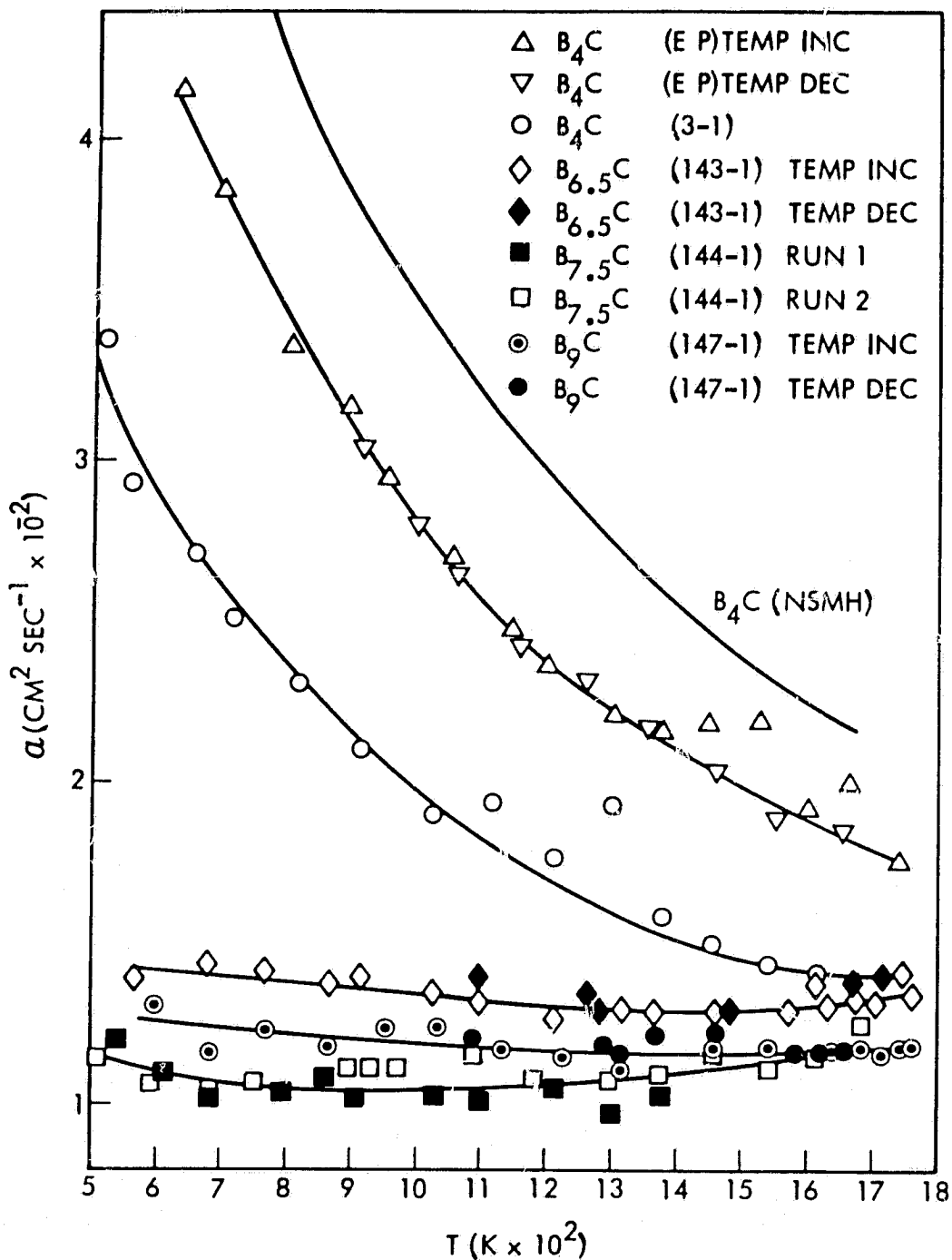


Fig. 1. The Thermal Diffusivity (α) of Boron Carbides as a Function of Temperature (T) ([EP] refers to Eagle Picher Commercial Grade Boron Carbide and [NSMH] to Nuclear Systems Materials Handbook data⁶).

with compositions ($0.1 < x < 0.2$) lying within the single-phase region are plotted against temperature in Fig. 1. The general consistency of measurements upon progressive heating of the sample (Temp Inc) with those with subsequent successive cooling (Temp Dec) indicates the insensitivity of these measurements to thermal cycling. Measurements of differently prepared samples of $B_{0.8}C_{0.2}$ (B_4C) are also compared in Fig. 1. Here significant differences in the magnitudes of the thermal diffusivities are found. Nonetheless, the temperature dependences of these thermal diffusivities are similar to one another.

The thermal conductivities (κ) were obtained from the thermal diffusivities (α) using the relationship $\kappa = C\alpha\rho$, where the specific heat, C , was obtained from the Elwell¹⁵ curves in Fig. 2 with C being treated as constant above 900 K. The sample densities (ρ) listed in Table 1 were determined by Archimedes principle and are compared to the theoretical values determined by Bouchacourt and Thevenot.¹¹ These thermal conductivity curves referred to the theoretical densities, are plotted in Fig. 3. Two further samples of $B_{0.9}C_{0.1}$, i.e., B_9C , (not shown in Fig. 1 for reasons of space) prepared by hot-pressing at higher pressures (~8000 to 9000 psi) for shorter periods (15 min) are also shown for comparison in Fig. 3. As illustrated both by the $B_{0.8}C_{0.2}$ and $B_{0.9}C_{0.1}$ samples, the magnitudes of the thermal conductivities depend upon the method of sample preparation. In addition, the thermal conductivity manifests a significant compositional dependence. Here both the magnitude and temperature dependence of the thermal conductivities vary significantly with composition.

Table 1. Boron Carbide Densities

Specimen	Experimental Density (gm/cm^3)	Percent Theoretical Density (gm/cm^3)
B_4C EP	2.44 ^a	97
B_4C 3-1	2.38	98
$B_{6.5}C(143-1)$	2.38	96
$B_{7.5}C(144-1)$	2.48	100
$B_9C(147-1)$	2.43	98
$B_9C(20-1)$	2.33	94

^aAverage of three samples.

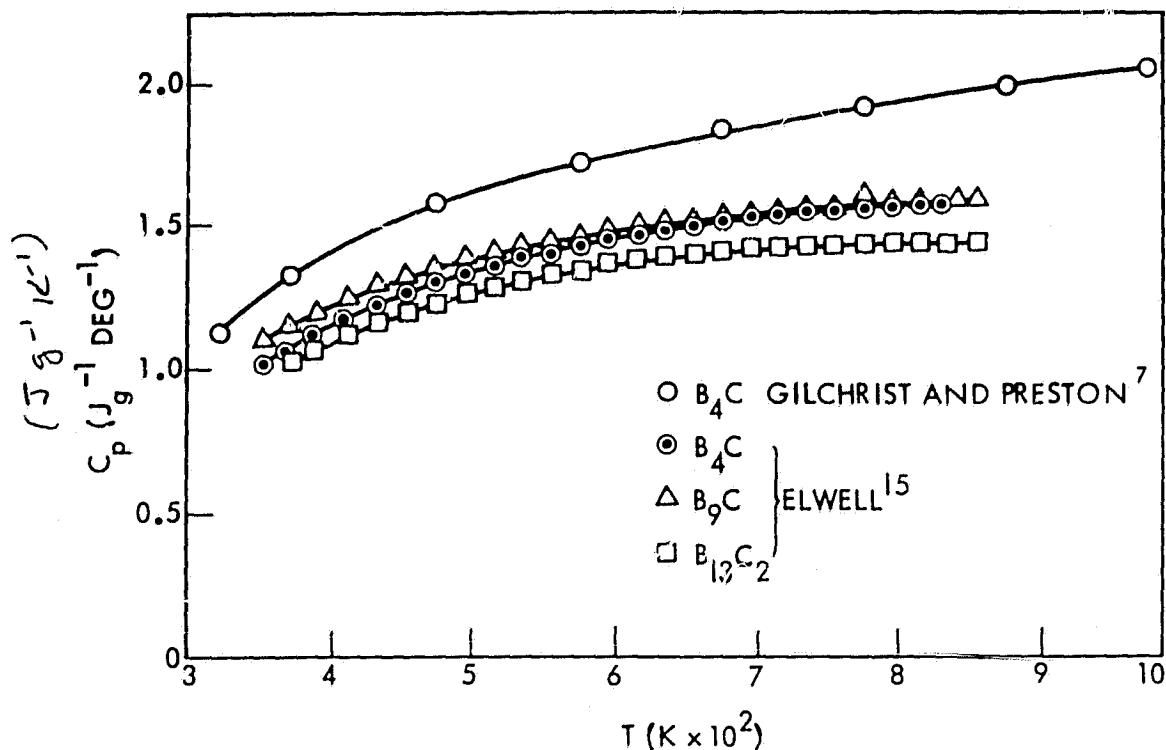


Fig. 2. The Specific Heat (C_p) of Boron Carbides vs Temperature (T)

It should be noted that we have utilized Elwell's specific heat data since his samples, while not ours, were prepared in a manner similar to ours. However, even if the specific heat were to differ substantially, (i.e., be such as those of Gilchrist and Preston of Fig. 2) the fall of the thermal conductivity of the $\text{B}_{0.8}\text{C}_{0.2}$ with increasing temperature would only be somewhat milder than that shown in Fig. 3. In fact, as shown in Fig. 3, the thermal conductivity of our $\text{B}_{0.8}\text{C}_{0.2}$ falls with increasing temperature in a manner similar to that found by other researchers.

DISCUSSION

The electrical transport properties of these boron carbides have been studied in detail.² It is concluded that the boron carbides are nearly degenerate semiconductors in which the predominant charge carriers (holes) form small polarons and hop between inequivalent positions in the solid. The dependence of the Seebeck coefficient on carbon concentration suggests that the holes hop between sites associated with carbon atoms. In this

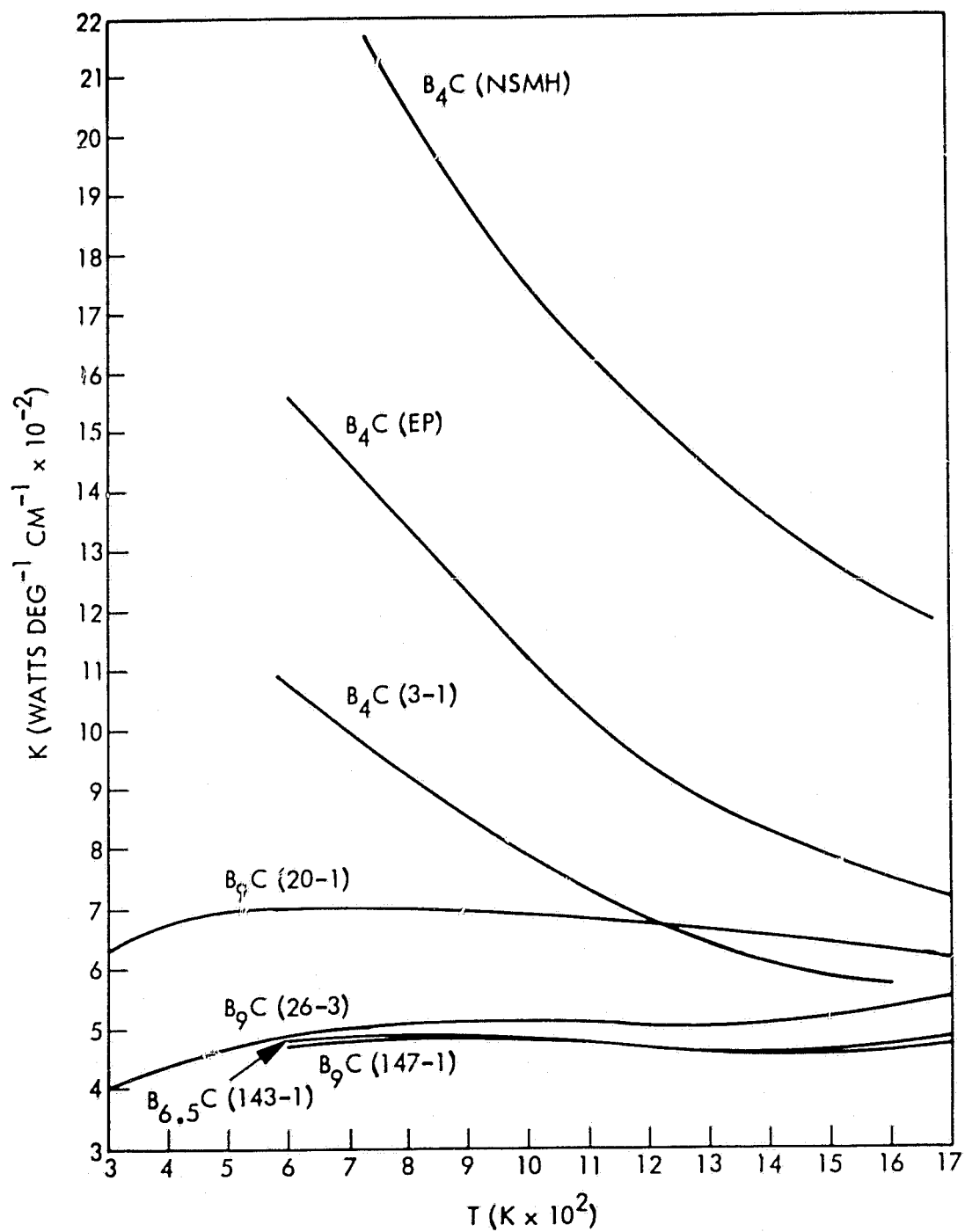


Fig. 3. The Thermal Conductivity (K) of Boron Carbides as a Function of Temperature (T)

case the inequivalence of hopping sites corresponds to jumps between chains and icosahedra. Thus carbon atoms occupy these two types of sites at all carbon compositions within the single-phase region. This contradicts the idea of some that $x = 0.133$ ($B_{13}C_2$) represents an "ideal" composition in which two carbon atoms reside on each intericosahedral chain, with the icosahedra remaining devoid of carbon atoms. The present thermal conductivity studies also supports the view that carbon atoms generally occupy both kinds of sites.

As shown in Fig. 3, the high temperature thermal conductivities of the boron carbides are generally moderately low (~ 0.1 to 0.01 W/K-cm at 1000 K). At the highest carbon concentrations, $x = 0.200$ (B_4C) the thermal conductivity is not only at its largest but also is a decreasing function of increasing temperature. At lower carbon concentrations, $x = 0.100$, 0.133 and 0.176 , the thermal conductivities are much smaller with much weaker temperature dependences. The smaller weakly temperature dependent thermal conductivities of these materials with lower carbon concentrations are similar to those of glasses (e.g., silica). However the thermal conductivity of the high-carbon concentration material ($x = 0.200$, B_4C) is characteristic of the lattice thermal conductivity of a crystal. This suggests that at the high carbon concentration carbon atoms occupy all available sites. In this situation the thermal transport should be that of a well ordered crystal. At lower carbon concentrations the carbon atoms occupy only a fraction of the available locations. The thermal transport through such a defect structure then resembles that through a disordered material. The fact that the thermal transport through the $x = 0.133$ composition ($B_{13}C_2$) resembles that through an amorphous structure belies this being an "ideal" composition with only chains being occupied by carbon atoms. Thus both the electronic and thermal transport suggests a consistent picture of the carbon occupancy of the boron carbides.

The thermal conductivity of these solids arises from two sources. First, even in the absence of charge carriers, heat is transferred directly between atoms of the solid. Second, the motion of a charge carrier through a solid can also be associated with a heat flow. In the boron carbides the electronic transport represents a very distinctive type of small-polaron hopping.^{1,2} The associated thermal conductivity is distinctive as well. In particular, vibrational energy is transported with a charge carrier as it hops between inequivalent sites. The average energy carried with a hopping carrier, E_T , is CT^2 , where the constant C is defined by $C = zJ^2/16E_D^3$, z is the number of nearest neighbors, J is the intersite transfer energy and E_D is the small-polaron binding energy characterizing an average site in the material. Thus the energy carried increases with temperature. Preliminary

considerations indicate that the electronic contribution to the thermal conductivity is a product of this energy, E_T , the electronic diffusion constant, D , and the rate of change of the carrier density with temperature (dn/dT), i.e., $\kappa_T = E_T D (dn/dT)$. This yields an electronic contribution to the thermal conductivity which increases with temperature and is ~ 15 mW/K-cm at 1600 K. This is about one third of the lowest value we measure.

Finally we note that the disorder in the masses and spring constants associated with carbon atoms being distributed among distinct sites can greatly alter the nature of the lattice contribution to the thermal conductivity. In particular, in this situation a significant fraction of the vibrational modes become localized. In a purely harmonic system these modes will not participate directly in the passage of vibrational energy. However, anharmonic forces provide a means of transferring energy between local and nonlocal vibrational modes. This facilitates the thermal transport. Hence, contrary to customary (phonon-scattering) treatments of thermal conductivity, the thermal conductivity increases as the anharmonic coupling strength increases. While such behavior has been shown in theoretical models,¹⁸ it has not, heretofore, been reported in actual solids. The boron carbides, $B_{1-x}C_x$, of low carbon concentrations (e.g., $x = 0.100, 0.133$ and 0.176) may be examples of this distinctive type of thermal transport. We are currently investigating this possibility further.

ACKNOWLEDGEMENTS

We wish to acknowledge the work of N. G. Elsner and G. H. Reynolds of GA Technologies for the materials preparation and A. Lockwood and J. Parker for density measurements.

REFERENCES

- *The research described in this paper was carried out by the Jet Propulsion Laboratory, California Institute of Technology, under contract with the National Aeronautics and Space Administration.
- **Supported by U.S. Department of Energy Contract No. DE-AC04-76CDP00789.
- 1. C. Wood and D. Emin, Bull. Amer. Phys. Soc. 28 553 (1873).
- 2. D. Emin and C. Wood, IECEC Conference, Orlando, FL Aug. 22-26, 1983.
- 3. H. W. Deem and C. F. Lucks, Battelle Memorial Institute Report No. BMI-731, 1951 (unpublished); Nucl. Sci. Abstr. 6, 915 (1952).

4. J. C. Hedge, C. Kostenko, and J. I. Lang, Illinois Institute of Technology Research Institute, Technical Documentary Report Nos. ASD-TDR-63-597 and AD-424375, 1963 (unpublished; see chem. Abstr. 61, 10433d 81964).
5. N. V. Boiko and E. E. Shpilrain, Sov. Phys. High Temp. 2, 493 (1964).
6. Nuclear Systems Materials Handbook, Vol. 1 Design Data. Part III Group 1 Section 1. p 1.0,1.1.
7. K. E. Gilchrist and S. D. Preston, High Temp.-High Press. 11 643 (1979).
8. K. H. Clark and J. L. Hoard, J. Amer. Chem. Soc. 65 2115 (1943).
9. G. Will and K. H. Kossobutzhi, J. Less-Comm. Met 47 43 1976.
10. H. L. Yakel, Acta Cryst. B31 1797 (1975).
11. J. Bouchacourt and F. Thevenot, J. Less-Comm Met 82 227 (1981).
12. W. J. Parker and R. J. Jenkins, C. P. Butler and G. L. Abbott, J. Appl. Phys. 32 1979 (1961).
13. R. E. Taylor, High-Temp.-High Press. 11 43 (1979).
14. M. L. Mingos, J. Heat Mass Transfer 17 1365 (1974).
15. Data supplied by D. Elwell, Stanford University, using a Dupont Differential Scanning Calorimeter.
16. From thermal diffusivity data supplied by R. E. Taylor, Purdue University, and confirmed by JPL, using the flash method. An absolute determination of thermal conductivity by G. Slack, G. E. Research, yielded a fairly emperature independent value of -0.068 ± 0.002 W/K-cm for $B_{0.9}C_{0.1}$ in the vicinity of room temperature in essential agreement with $B_{0.9}C_{0.1}$ (20-1).
17. D. N. Payton, M. Rich and W. M. Visscher, Phys. Rev. 160, 706 (1967).